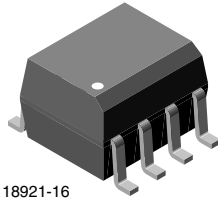
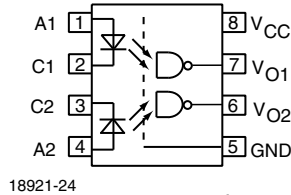


## High Speed Optocoupler, 10 MBd, Dual, SOIC-8 Package



18921-16



18921-24



20050

### DESCRIPTION

The SFH675xT-series, is a dual channel 10 MBd optocoupler utilizing a high efficient input LED coupled with an integrated optical photodiode IC detector. The detector has an open drain NMOS-transistor output, providing less leakage compared to an open collector Schottky clamped transistor output. The internal shield provides a guaranteed common mode transient immunity of 5 kV/μs for the SFH6756T and 15 kV/μs for the SFH6757T. The use of a 0.1 μF bypass capacitor connected between pin 5 and 8 is recommended.

### AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- cUL - file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-5 (VDE 0884) available with option 1

### FEATURES

- Choice of CMR performance of 15 kV/μs, 5 kV/μs, and 100 V/μs
- External creepage distance > 5 mm
- High speed: 10 Mbd typical
- + 5 V CMOS compatibility
- Guaranteed AC and DC performance over temperature: - 40 °C to + 100 °C temperature range
- Pure tin leads
- Meets IEC 60068-2-42 (SO<sub>2</sub>) and IEC 60068-2-43 (H<sub>2</sub>S) requirements
- Low input current capability: 5 mA
- Compliant to RoHS Directive to 2002/95/EC and in accordance WEEE 2002/96/EC

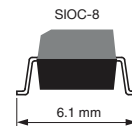
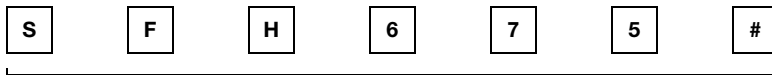


**RoHS**  
COMPLIANT

### APPLICATIONS

- Microprocessor system interface
- PLC, ATE input/output isolation
- Computer peripheral interface
- Digital fieldbus isolation: CC-link, DeviceNet, profibus, SDS
- High speed A/D and D/A conversion
- AC plasma display panel level shifting
- Multiplexed data transmission
- Digital control power supply
- Ground loop elimination

### ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CMR (kV/μs)	CMR (kV/μs)	CMR (kV/μs)
UL, cUL	0.1	5	15
SOIC-8	SFH6755T	SFH6756T	SFH6757T

### TRUTH TABLE (positive logic)

LED	ENABLE	OUTPUT
On	H	L
Off	H	H
On	L	H
Off	L	H
On	NC	L
Off	NC	H

# SFH6755T, SFH6756T, SFH6757T



Vishay Semiconductors High Speed Optocoupler, 10 MBd,  
Dual, SOIC-8 Package

<b>ABSOLUTE MAXIMUM RATINGS</b> <sup>(1)</sup> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Average forward current (single channel)		$I_F$	20	mA
Average forward current (per channel for dual channel)		$I_F$	15	mA
Reverse input voltage		$V_R$	5	V
Surge current	$t = 100\text{ }\mu\text{s}$	$I_{FSM}$	200	mA
Output power dissipation (single channel)		$P_{diss}$	35	mW
Output power dissipation (per channel for dual)		$P_{diss}$	25	mW
<b>OUTPUT</b>				
Supply voltage	1 min maximum	$V_{CC}$	7	V
Output current		$I_O$	50	mA
Output voltage		$V_O$	7	V
Output power dissipation (single channel)		$P_{diss}$	85	mW
Output power dissipation (for dual channel)		$P_{diss}$	60	mW
<b>COUPLER</b>				
Isolation test voltage	$t = 1\text{ s}$	$V_{ISO}$	4000	$V_{RMS}$
Storage temperature		$T_{stg}$	- 55 to + 150	$^{\circ}\text{C}$
Operating temperature		$T_{amb}$	- 40 to + 100	$^{\circ}\text{C}$
Lead solder temperature	for 10 s		260	$^{\circ}\text{C}$
Solder reflow temperature <sup>(2)</sup>	for 1 min	$T_{sld}$	260	$^{\circ}\text{C}$

## Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- Refer to reflow profile for soldering conditions for surface mounted devices.

<b>RECOMMENDED OPERATING CONDITIONS</b>					
PARAMETER	TEST CONDITION	SYMBOL	MIN.	MAX.	UNIT
Operating temperature		$T_{amb}$	- 40	100	$^{\circ}\text{C}$
Supply voltage		$V_{CC}$	4.5	5.5	V
Input current low level		$I_{FL}$	0	250	$\mu\text{A}$
Input current high level		$I_{FH}$	5	15	mA
Output pull up resistor		$R_L$	330	4K	$\Omega$
Fanout	$R_L = 1\text{ k}\Omega$	N		5	-

<b>THERMAL CHARACTERISTICS</b>					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
LED power dissipation	at 25 $^{\circ}\text{C}$	$P_{diss}$	100	mW	
Output power dissipation	at 25 $^{\circ}\text{C}$	$P_{diss}$	500	mW	
Maximum LED junction temperature		$T_{jmax}$	125	$^{\circ}\text{C}$	
Maximum output die junction temperature		$T_{jmax}$	125	$^{\circ}\text{C}$	
Thermal resistance, junction emitter to emitter		$\theta_{EE}$	412	$^{\circ}\text{C}/\text{W}$	
Thermal resistance, junction detector to emitter		$\theta_{DE}$	133	$^{\circ}\text{C}/\text{W}$	
Thermal resistance, junction emitter to board		$\theta_{EB}$	120	$^{\circ}\text{C}/\text{W}$	
Thermal resistance, junction detector to board		$\theta_{DB}$	77	$^{\circ}\text{C}/\text{W}$	
Thermal resistance, junction emitter to case		$\theta_{EC}$	110	$^{\circ}\text{C}/\text{W}$	

## Note

- The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's Thermal Characteristics of Optocouplers application note.

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , and $V_{CC} = 5.5\text{ V}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Input forward voltage	$I_F = 10\text{ mA}$	$V_F$	1.1	1.4	1.7	V
Reverse current	$V_R = 5\text{ V}$	$I_R$		0.01	10	$\mu\text{A}$
Input capacitance	$f = 1\text{ MHz}$ , $V_F = 0\text{ V}$	$C_I$		55		pF
<b>OUTPUT</b>						
High level supply current (single channel)	$V_E = 0.5\text{ V}$ , $I_F = 0\text{ mA}$	$I_{CCH}$		4.1	7	mA
	$V_E = V_{CC}$ , $I_F = 0\text{ mA}$	$I_{CCH}$		3.3	6	mA
High level supply current (dual channel)	$I_F = 0\text{ mA}$	$I_{CCH}$		6.5	12	mA
Low level supply current (single channel)	$V_E = 0.5\text{ V}$ , $I_F = 10\text{ mA}$	$I_{CCL}$		4	7	mA
	$V_E = V_{CC}$ , $I_F = 10\text{ mA}$	$I_{CCL}$		3.3	6	mA
Low level supply current (dual channel)	$I_F = 10\text{ mA}$	$I_{CCL}$		6.5	12	mA
High level output current	$V_E = 2\text{ V}$ , $V_O = 5.5\text{ V}$ , $I_F = 250\text{ }\mu\text{A}$	$I_{OH}$		0.002	1	$\mu\text{A}$
Low level output voltage	$V_E = 2\text{ V}$ , $I_F = 5\text{ mA}$ , $I_{OL}(\text{sinking}) = 13\text{ mA}$	$V_{OL}$		0.2	0.6	V
Input threshold current	$V_E = 2\text{ V}$ , $V_O = 5.5\text{ V}$ , $I_{OL}(\text{sinking}) = 13\text{ mA}$	$I_{TH}$		2.4	5	mA

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

<b>SWITCHING CHARACTERISTICS (1)</b>						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Propagation delay time to high output level	$R_L = 350\text{ }\Omega$ , $C_L = 15\text{ pF}$	$t_{PLH}$	20	48	100	ns
Propagation delay time to low output level	$R_L = 350\text{ }\Omega$ , $C_L = 15\text{ pF}$	$t_{PHL}$	25	50	100	ns
Pulse width distortion	$R_L = 350\text{ }\Omega$ , $C_L = 15\text{ pF}$	$ t_{PHL} - t_{PLH} $		2.9	35	ns
Propagation delay skew	$R_L = 350\text{ }\Omega$ , $C_L = 15\text{ pF}$	$t_{PSK}$		8	40	ns
Output rise time (10 to 90 %)	$R_L = 350\text{ }\Omega$ , $C_L = 15\text{ pF}$	$t_r$		23		ns
Output fall time (90 to 10 %)	$R_L = 350\text{ }\Omega$ , $C_L = 15\text{ pF}$	$t_f$		7		ns

**Note**

- (1) Over recommended temperature ( $T_A = -40\text{ }^{\circ}\text{C}$  to  $+100\text{ }^{\circ}\text{C}$ ),  $V_{CC} = 5\text{ V}$ ,  $I_F = 7.5\text{ mA}$  unless otherwise specified. All typicals at  $T_{amb} = 25\text{ }^{\circ}\text{C}$ ,  $V_{CC} = 5\text{ V}$ .

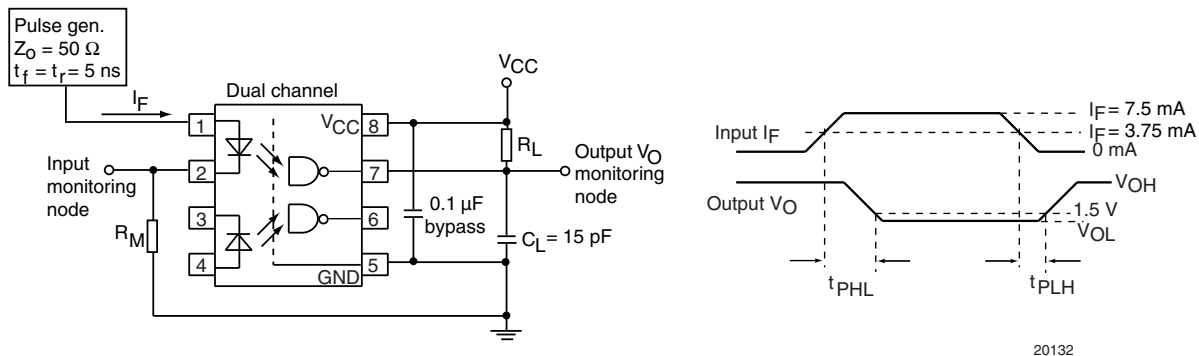


Fig. 1 - Dual Channel Test Circuit for  $t_{PLH}$ ,  $t_{PHL}$ ,  $t_r$  and  $t_f$

# SFH6755T, SFH6756T, SFH6757T



Vishay Semiconductors High Speed Optocoupler, 10 MBd,  
Dual, SOIC-8 Package

COMMON MODE TRANSIENT IMMUNITY						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Common mode transient immunity (high)	$ V_{CM}  = 10\text{ V}$ , $V_{CC} = 5\text{ V}$ , $I_F = 0\text{ mA}$ , $V_{O(\min.)} = 2\text{ V}$ , $R_L = 350\ \Omega$ , $T_{amb} = 25\text{ }^\circ\text{C}$ (1)	$ CM_H $	100			V/ $\mu\text{s}$
	$ V_{CM}  = 50\text{ V}$ , $V_{CC} = 5\text{ V}$ , $I_F = 0\text{ mA}$ , $V_{O(\min.)} = 2\text{ V}$ , $R_L = 350\ \Omega$ , $T_{amb} = 25\text{ }^\circ\text{C}$ (2)	$ CM_H $	5000	10 000		V/ $\mu\text{s}$
	$ V_{CM}  = 1\text{ kV}$ , $V_{CC} = 5\text{ V}$ , $I_F = 0\text{ mA}$ , $V_{O(\min.)} = 2\text{ V}$ , $R_L = 350\ \Omega$ , $T_{amb} = 25\text{ }^\circ\text{C}$ (3)	$ CM_H $	15 000	25 000		V/ $\mu\text{s}$
Common mode transient immunity (low)	$ V_{CM}  = 10\text{ V}$ , $V_{CC} = 5\text{ V}$ , $I_F = 7.5\text{ mA}$ , $V_{O(\max.)} = 0.8\text{ V}$ , $R_L = 350\ \Omega$ , $T_{amb} = 25\text{ }^\circ\text{C}$ (1)	$ CM_L $	100			V/ $\mu\text{s}$
	$ V_{CM}  = 50\text{ V}$ , $V_{CC} = 5\text{ V}$ , $I_F = 7.5\text{ mA}$ , $V_{O(\max.)} = 0.8\text{ V}$ , $R_L = 350\ \Omega$ , $T_{amb} = 25\text{ }^\circ\text{C}$ (2)	$ CM_L $	5000	10 000		V/ $\mu\text{s}$
	$ V_{CM}  = 1\text{ kV}$ , $V_{CC} = 5\text{ V}$ , $I_F = 7.5\text{ mA}$ , $V_{O(\max.)} = 0.8\text{ V}$ , $R_L = 350\ \Omega$ , $T_{amb} = 25\text{ }^\circ\text{C}$ (3)	$ CM_L $	15 000	25 000		V/ $\mu\text{s}$

### Notes

- (1) For SFH6755T
- (2) For SFH6756T
- (3) For SFH6757T

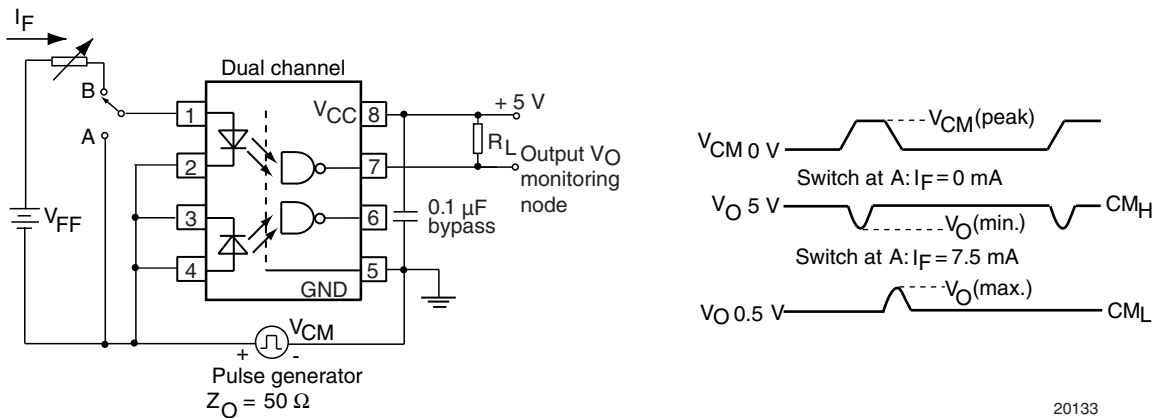


Fig. 2 - Dual Channel Test Circuit for Common Mode Transient Immunity

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
Peak transient overvoltage		$V_{IOTM}$	6000			V
Peak insulation voltage		$V_{IORM}$	560			V
Safety rating - power output		$P_{SO}$			350	mW
Safety rating - input current		$I_{SI}$			150	mA
Safety rating - temperature		$T_{SI}$			165	$^\circ\text{C}$
Creepage distance			5			mm
Clearance distance			4			mm
Insulation thickness			0.2			mm

### Note

- As per IEC 60747-5-5, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



# SFH6755T, SFH6756T, SFH6757T

High Speed Optocoupler, 10 MBd, Vishay Semiconductors  
Dual, SOIC-8 Package

## TYPICAL CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

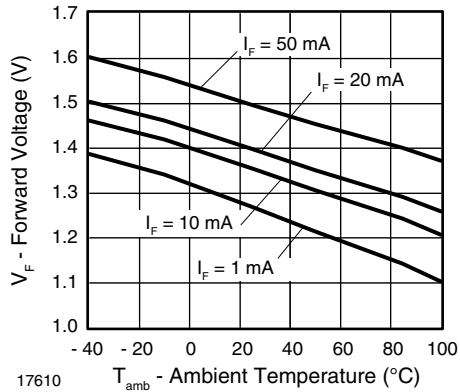


Fig. 3 - Forward Voltage vs. Ambient Temperature

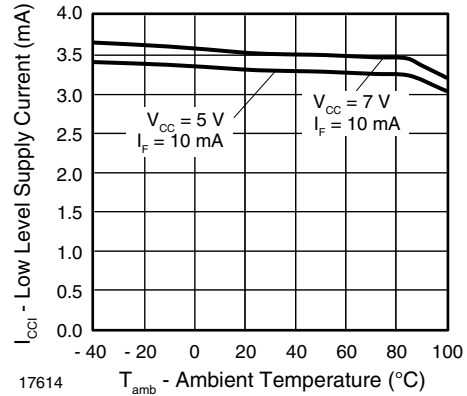


Fig. 6 - Low Level Supply Current vs. Ambient Temperature

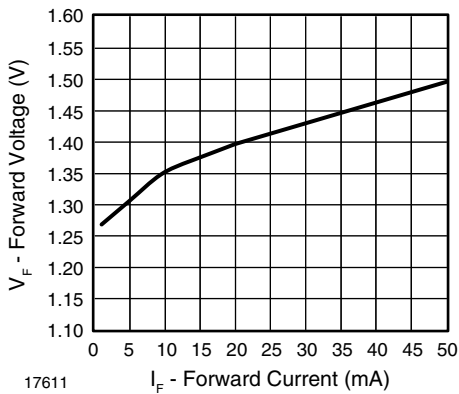


Fig. 4 - Forward Voltage vs. Forward Current

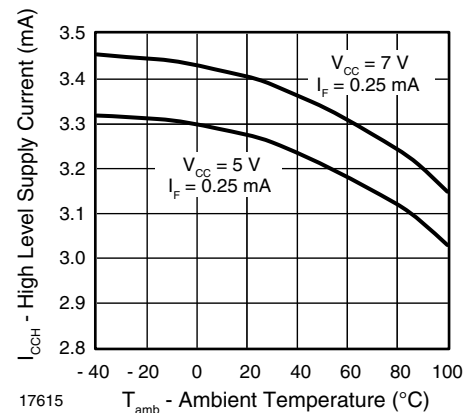


Fig. 7 - High Level Supply Current vs. Ambient Temperature

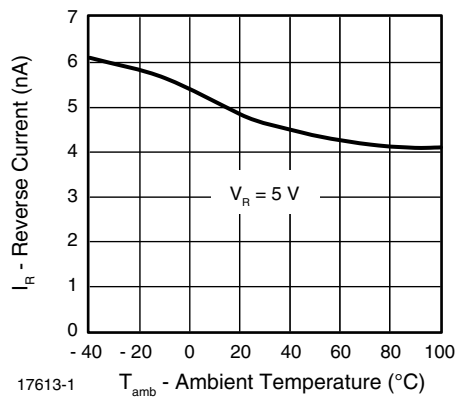


Fig. 5 - Reverse Current vs. Ambient Temperature

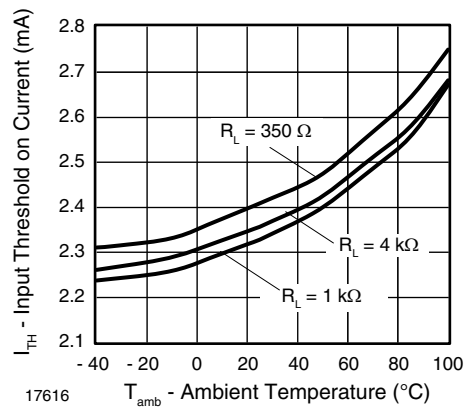


Fig. 8 - Input Threshold on Current vs. Ambient Temperature

# SFH6755T, SFH6756T, SFH6757T



Vishay Semiconductors High Speed Optocoupler, 10 MBd,  
Dual, SOIC-8 Package

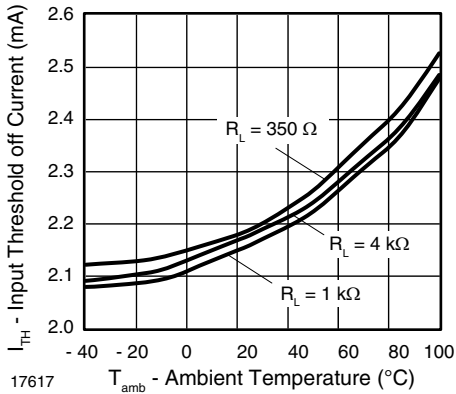


Fig. 9 - Input Threshold off Current vs. Ambient Temperature

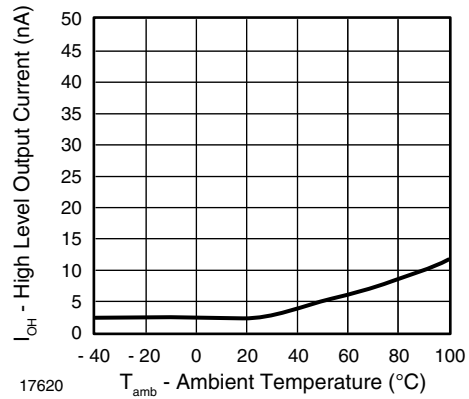


Fig. 12 - High Level Output Current vs. Ambient Temperature

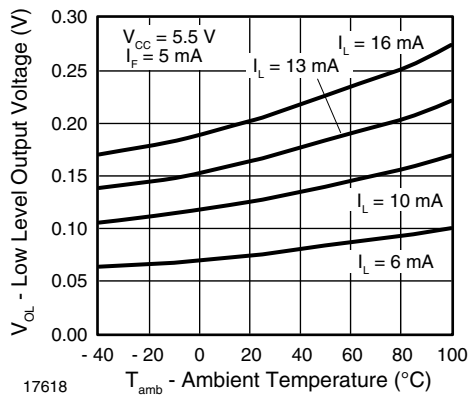


Fig. 10 - Low Level Output Voltage vs. Ambient Temperature

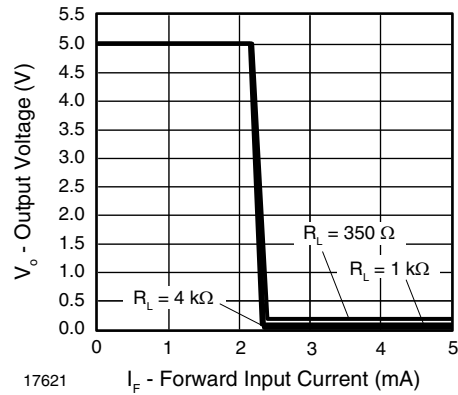


Fig. 13 - Output Voltage vs. Forward Input Current

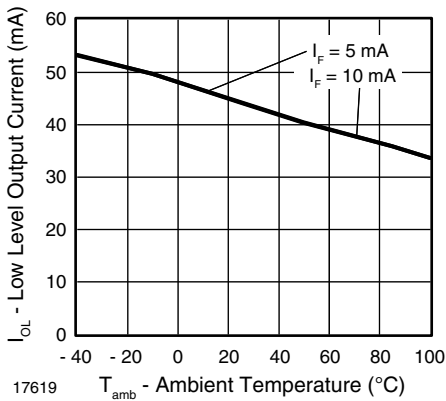


Fig. 11 - Low Level Output Current vs. Ambient Temperature

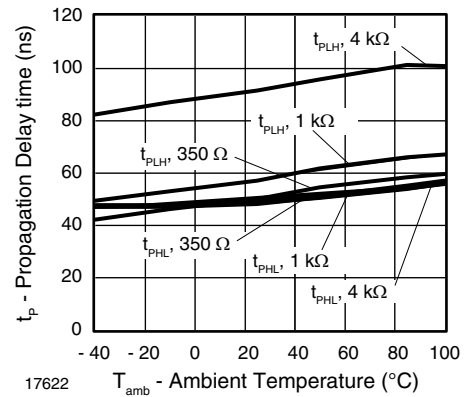


Fig. 14 - Propagation Delay vs. Ambient Temperature



# SFH6755T, SFH6756T, SFH6757T

High Speed Optocoupler, 10 MBd, Vishay Semiconductors  
Dual, SOIC-8 Package

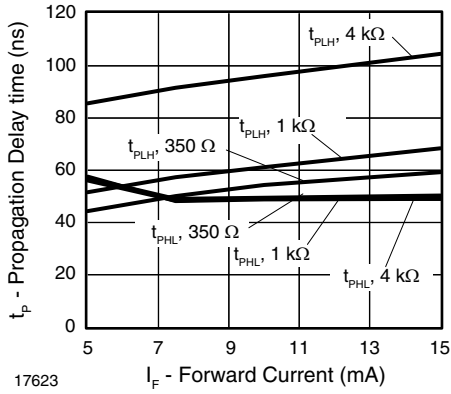


Fig. 15 - Propagation Delay vs. Forward Current

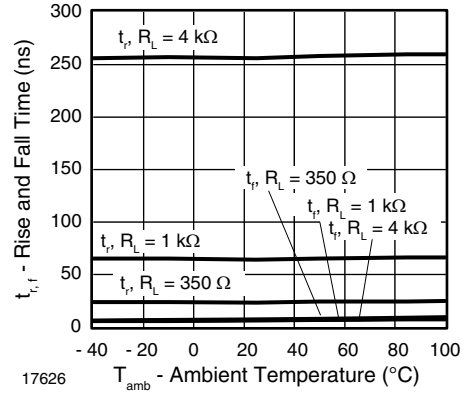


Fig. 18 - Rise and Fall Time vs. Ambient Temperature

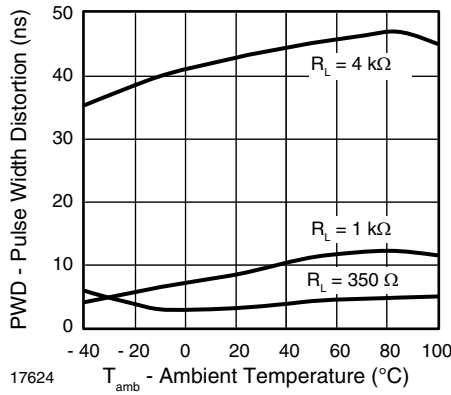


Fig. 16 - Pulse Width Distortion vs. Ambient Temperature

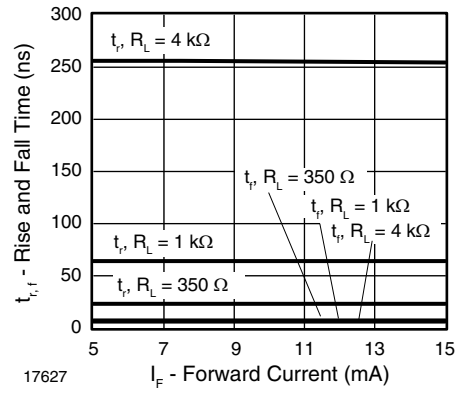


Fig. 19 - Rise and Fall Time vs. Forward Current

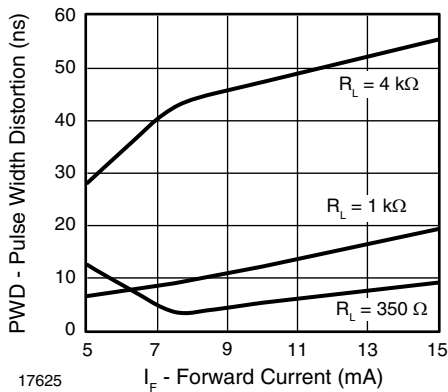


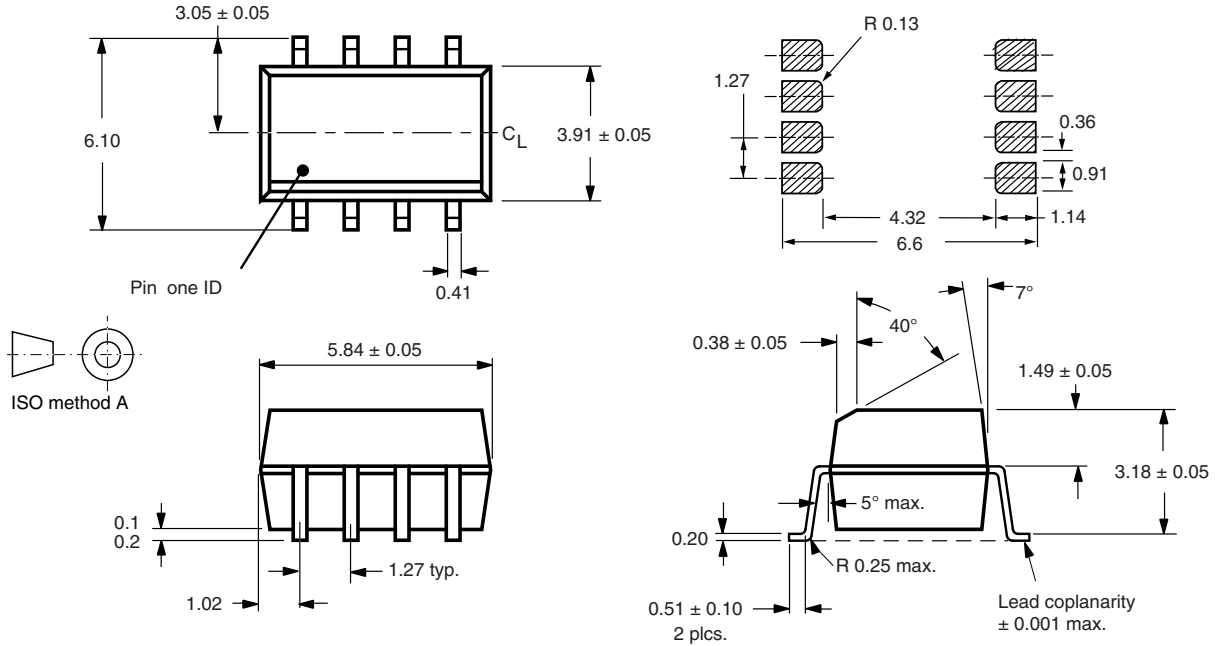
Fig. 17 - Pulse Width Distortion vs. Forward Current

# SFH6755T, SFH6756T, SFH6757T



Vishay Semiconductors High Speed Optocoupler, 10 MBd,  
Dual, SOIC-8 Package

## PACKAGE DIMENSIONS millimeters DUAL CHANNEL SOIC-8



i178020

## ESD CAUTION

This is an ESD (electro static discharge) sensitive device. Electrostatic charges accumulate on the human body and test equipment and can discharge without detection. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality. ESD withstand voltage of this device is up to 1500 V acc. to JESD22-A114-B.





## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.